



中国科学院半导体研究所

中国科学院半导体材料科学重点实验室

低维半导体材料与器件北京市重点实验室

首页 实验室概况 最新动态 在研项目 研究进展 开放课题 学术交流

科研成果

获奖成果 (2000年以后)

个人荣誉 (2000年以后)

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授权发明专利

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SEARCH

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其他子站链接

选择链接

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2008-05-23

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